

TOSHIBA PHOTOCOUPLER PHOTO RELAY

# TLP179D

## MEASUREMENT INSTRUMENTS

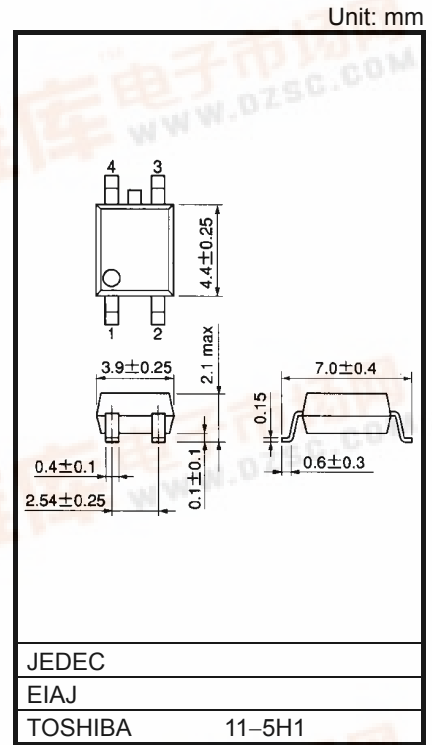
LOGIC IC TESTERS / MEMORY TESTERS

BOARD TESTERS / SCANNERS

The TOSHIBA TLP179D Mini-flat photorelay is a small-outline photorelay, suitable for surface-mount assembly. The TLP179D consists of a GaAs infrared-emitting diode optically coupled to a photo-MOS FET and housed in a 4-pin package. Its characteristics include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency measurement instruments.

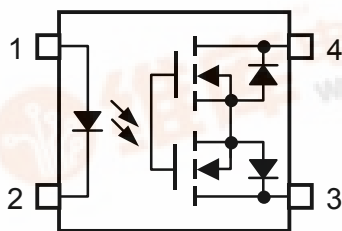
## FEATURES

- 4 pin SOP (2.54SOP4) : 2.1 mm high, 2.54 mm pitch
- 1-Form-A
- Peak Off-State Voltage : 200 V (min)
- Trigger LED Current : 3 mA (max)
- On-State Current : 50 mA (max)
- On-State Resistance : 50 Ω (max)
- Output Capacitance : 20 pF (max)
- Isolation Voltage : 1500 Vrms (min)



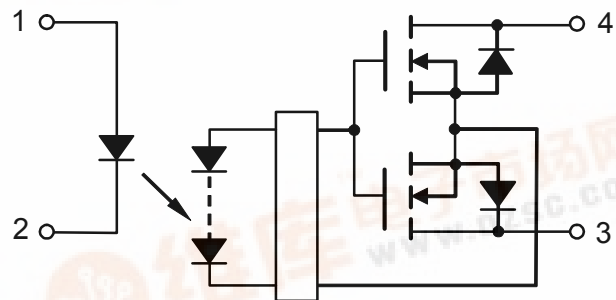
Weight: 0.1 g

## PIN CONFIGURATION (TOP VIEW)



- 1 : ANODE
- 2 : CATHODE
- 3 : DRAIN
- 4 : DRAIN

## SCHEMATIC



## Absolute MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	$I_F$	50	mA
	Forward Current Derating (Ta ≥ 25°C)	$\Delta I_F/^\circ\text{C}$	-0.5	mA/°C
	Reverse Voltage	$V_R$	5	V
	Junction Temperature	$T_j$	125	°C
DETECTOR	Off-State Output Terminal Voltage	$V_{OFF}$	200	V
	On-State Current	$I_{ON}$	50	mA
	On-State Current Derating (Ta ≥ 25°C)	$\Delta I_{ON}/^\circ\text{C}$	-0.5	mA/°C
	Junction Temperature	$T_j$	125	°C
Storage Temperature Range		$T_{stg}$	-55~125	°C
Operating Temperature Range		$T_{opr}$	-40~85	°C
Lead Soldering Temperature (10 s)		$T_{sol}$	260	°C
Isolation Voltage (AC, 1 minute, R.H. ≤ 60%) (NOTE1)		$BV_S$	1500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(NOTE1): Device considered a two-terminal device : LED side pins shorted together, and DETECTOR side pins shorted together.

## RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	Min	Typ.	Max	UNIT
Supply Voltage	$V_{DD}$	—	—	160	V
Forward Current	$I_F$	5	7.5	15	mA
On-State Current	$I_{ON}$	—	—	50	mA
Operating Temperature	$T_{opr}$	-20	—	60	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

## INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	Min	Typ.	Max	UNIT
LED	Forward Voltage	$V_F$	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	$I_R$	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	$C_T$	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Off-State Current	$I_{OFF}$	$V_{OFF} = 160 \text{ V}$	—	—	1	nA
	Capacitance	$C_{OFF}$	$V = 0, f = 1 \text{ MHz}$	—	15	20	pF

**COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	Min	Typ.	Max	UNIT
Trigger LED Current	I <sub>FT</sub>	I <sub>ON</sub> = 50 mA	—	1	3	mA
Return LED Current	I <sub>FC</sub>	I <sub>OFF</sub> = 100 μA	0.1	—	—	mA
On-State Resistance	R <sub>ON</sub>	I <sub>ON</sub> = 50 mA, I <sub>F</sub> = 5 mA	—	40	50	Ω

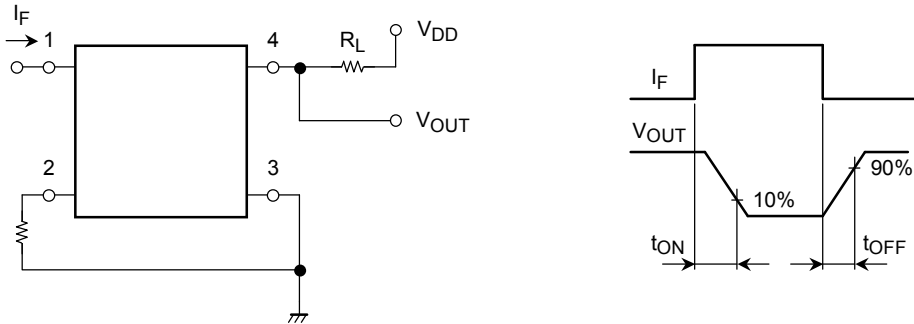
**ISOLATION CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	Min	Typ.	Max	UNIT
Capacitance Input to Output	C <sub>S</sub>	V <sub>S</sub> = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation Resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	—	Ω
Isolation Voltage	BV <sub>S</sub>	AC, 1 minute	1500	—	—	V <sub>rms</sub>
		AC, 1 second (in oil)	—	3000	—	—
		DC, 1 minute (in oil)	—	3000	—	V <sub>dc</sub>

**SWITCHING CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	Min	Typ.	Max	UNIT
Turn-on Time	t <sub>ON</sub>	R <sub>L</sub> = 200 Ω (NOTE 2)	—	0.03	0.5	ms
Turn-off Time	t <sub>OFF</sub>	V <sub>DD</sub> = 10 V, I <sub>F</sub> = 5 mA	—	0.07	0.2	

(NOTE 2) : SWITCHING TIME TEST CIRCUIT



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